## Journal of Materials Chemistry

Cite this: J. Mater. Chem., 2012, 22, 328

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### COMMUNICATION

# Micro and nanopatterning of functional materials on flexible plastic substrates *via* site-selective surface modification using oxygen plasma<sup>†</sup>

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Received 1st October 2011, Accepted 9th November 2011 DOI: 10.1039/c1jm14931h

A simple and cost effective methodology for large area micro and nanopatterning of a wide range of functional materials on flexible substrates is presented. A hydrophobic-hydrophilic chemical contrast was patterned on surfaces of various flexible plastic substrates using molds and shadow masks with which selected areas of the substrate surface were shielded from exposure to oxygen plasma. The exposed areas became hydrophilic and were used as templates for site-selective adsorption, electroless deposition and solution phase deposition of functional materials like ZnO, Ag thin films, Au nanoparticles, conducting polymers, titania and ZnO nanowires. The patterned surfaces and functional materials were characterized by scanning electron microscopy, X-ray diffraction and atomic force microscopy.

#### Introduction

Flexible polymeric substrates are important in novel roll-to-roll manufacturing technologies. Plastic substrates are ideal candidates for ultra-light electronic devices, personal health monitors and ultrathin foldable display screens due to their flexibility, low weight and inexpensiveness. In order to realize functional flexible devices, the ability to pattern various materials such as conducting polymers, metals and metal oxides in the form of thin films, nanoparticle assemblies, or nanowire arrays is crucial. To ensure high yield and low cost production, the availability of cost-effective, low temperature patterning processes under mild chemical conditions is required. Conventional device fabrication approaches such as photolithography, chemical vapor deposition or wet/dry etching often require a clean room and are not always compatible with plastic substrates due to the instability of organic polymers in such process environments.

Recent methodologies such as surface modification,<sup>1</sup> material transfer<sup>2</sup> and self-assembly<sup>3</sup> are ideal to combine with plastic substrates, due to their technical simplicity and mild processing conditions. Site-selective surface modification of flexible substrates,

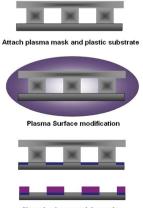
† Electronic supplementary information (ESI) available: Experimental section. See DOI: 10.1039/c1jm14931h

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followed by local immobilization or growth of materials is an ideal strategy for patterning functional materials on flexible substrates. In the present paper we employed different templates such as soft lithographic polydimethylsiloxane (PDMS) molds and silicon-based micro/nano stencil shadow masks to pattern flexible substrates like PDMS, polycarbonate (PC) and polyethylene terephtalate (PET) site-selectively using oxygen plasma. The patterned substrates are used for area-selective deposition of functional polymeric, metallic and ceramic materials.

A schematic diagram of the patterning process is shown in Fig. 1a. First conformal contact is made between the shielding template, *i.e.*, a patterned soft lithographic PDMS mold with connected channel structure or a silicon-based shadow mask, and the flexible polymeric substrate. The substrate-template assembly is then exposed to oxygen plasma. The plasma diffuses and reaches all non-shielded areas where it oxidizes the substrate surface, so that it becomes polar and hydrophilic. The regions on the substrate that are in conformal contact with the protruding parts of the PDMS mold or the shadow mask are protected from surface modification and remain hydrophobic.

After the prepatterning step, functional materials are selectively patterned onto the hydrophilic areas *via* electroless deposition, siteselective de-wetting, colloidal self-assembly and/or solution phase deposition. We demonstrate the versatility of our approach by patterning a wide range of functional materials such as ZnO, ZnO



Site selective material growth

Fig. 1 Schematic diagram of the channel diffused plasma patterning process and plasma modification.

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nanowires,  $TiO_2$ , silver, gold nanoparticles and the conducting polymer poly(2,3-dihydrothieno-1,4-dioxin)-poly(styrene sulfonate) (PEDOT:PSS) on length scales down to a few hundred nanometres.

#### **Results and discussion**

Oxygen plasma treatment is commonly used as a technique to clean substrates<sup>4,5,6</sup> and chemically modify surfaces to promote the wetting properties.<sup>4,7</sup> In soft lithographic approaches like micromolding in capillaries (MIMIC) and microtransfer molding (µTM), oxygen plasma is used to increase the surface energy of the PDMS surface to improve the wetting and/or promote the flow of sol-gel precursor solutions in PDMS channels.<sup>5,6,7</sup> Exposure of plastic surfaces such as PET, PC, and poly-methyl-methacrylate (PMMA) to oxygen plasmas creates surface -CO and -COOH groups which are responsible for the increased hydrophilicity of the exposed surface.<sup>8,9,10</sup> Also slight etching and roughening was observed on the polymeric PET and PC substrates due to the exposure to oxygen plasma. However, the etch rates were low as 0.5 nm min<sup>-1</sup>. In the case of PDMS, plasma exposure yields a silica  $(SiO_x)$ -like brittle surface.<sup>11</sup> All surfaces returned to their previous hydrophobic state in the course of time after exposure.<sup>8,9,11</sup>

The inset of Fig. 2a shows an HR-SEM image of a microstencil that we used for our experiments and Fig. 2a itself shows an HR-SEM image of a plasma-patterned PDMS substrate using the same microstencil. The stencil has perforations of 5 µm; the oxidized dots on the PDMS substrate have the same diameter. Fig. 2b shows plasma-patterned PDMS substrates using nanostencils with 400 nm perforations. Nanostencil lithography was only possible on PDMS substrates since the elasticity of the PDMS allowed to make good conformal contact between stencil and substrate. On other substrates such as PC and PET we used micro and nanopatterned PDMS molds to guide the oxygen plasma inside the channels between substrate and mold to form a chemically contrasted prepatterned substrate onto which complex oxide patterns were formed in a subsequent deposition step. The plasma diffusion process inside the PDMS channels is time and geometry-dependent.<sup>12,13</sup> A substantial degree of chemical

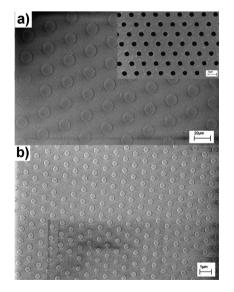


Fig. 2 a) HR-SEM images of PDMS substrate after plasma patterning using microstencil with 5  $\mu$ m perforations shown in the inset; b) PDMS substrates with 400 nm wide oxidized dots.

modification could be achieved by plasma exposure over an area of  $1 \times 1$  cm<sup>2</sup> within 10 min of exposure. The same molds could be reused for many patterning cycles without loss of quality of the replicated patterns. We tested different PDMS mold pattern geometries, including straight lines and interconnected network-type channel structures such as square grids, circular grids and honeycomb-type channel arrays. Optical microscopy examination confirmed that surface modification occurs faster when connected channel structures (circular grid, square grid, honeycomb patterns, etc.) were used, when compared to pattern geometries derived from non-connected channel structures (straight lines, zigzag lines, etc.). Modification times of up to 15-20 min were required to modify 8 mm long straight channels. We also examined PDMS molds with different height-to-width aspect ratios to determine the dependence of the plasma diffusion rate on aspect ratio. PDMS channels with a higher aspect ratio allowed faster diffusion of plasma, so that substantial diffusion distances could be accomplished in less time. The results are in agreement with a similar strategy, reported by Langowski et al., to prepattern a hydrophobic-hydrophilic contrast prior to deposition of biomolecular inks.1

ZnO thin films were deposited on plasma patterned silver seeded regions of the substrate following the recipe of Izaki and Omi.14 The film growth mechanism is explained in detail in ref. [14]. First a silver seeding step was employed to attach silver ions to the oxidized areas of the substrate and followed by a photoreduction step to convert the silver ions to silver particles. The silver particles acted as nucleation sites for ZnO growth. Fig. 3a shows a zigzag line pattern of ZnO formed on plasma modified silver seeded regions of a PET substrate. Fig. 3b show high aspect ratio honeycomb patterns of ZnO grown on a PDMS substrate. The hydrophobic non-seeded regions of the substrates were almost free from ZnO. However, a few small particles of ZnO were found in the non-seeded areas. These were attributed to homogeneously nucleated particles from the growth solution. To illustrate the versatility of the technique we used different pattern geometries, including lines, dots, grids and honeycomb patterns. The SEM images in Fig. 3 show that nucleation took place within the plasma modified and seeded regions of the substrate.

Fig. 3c show the tapping mode AFM height profile of high aspect ratio ZnO pattern on PDMS substrate, corresponding to the SEM images of Fig. 3b. A ZnO film of  $\sim 2 \mu m$  thickness formed on the plasma-modified silver seeded areas after 5 h of deposition time. The wurtzite phase of ZnO was confirmed by the XRD diffractogram in Fig. 3d. The rate of deposition was approximately 5–6 nm min<sup>-1</sup>, independent of deposition time. However, the SEM images showed that during the initial 15–30 min of film growth the film density was not uniform. Longer deposition times yielded more uniformly covered films.

Fig. 3e and 3f shows SEM images of ZnO nanowires deposited on plasma-patterned regions of the PDMS substrate. The ZnO nanowires were grown according to the method of Greene *et al.*<sup>15</sup> First, a ZnO seed growth step was performed by immersing the plasma patterned substrates in a 0.5 mol dm<sup>-3</sup> ethanolic solution of zinc acetate, followed by drying at 80 °C for 1 h. A subsequent oxygen plasma treatment was employed to convert the zinc acetate phase to ZnO seed particles. Then the substrates were kept floating on the surface of the nutrient solution, with the ZnO-seeded side facing downward into the solution at 80 °C. This was essential to avoid any deposition of homogeneously nucleated material on the substrate.

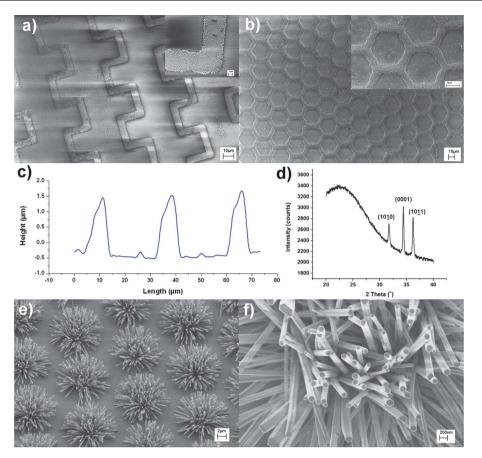


Fig. 3 SEM images of ZnO patterns formed by area-selective electroless deposition on plasma-modified Ag-seeded regions on PDMS and PET substrates. a) Zigzag line pattern of ZnO on PET substrate, line width 5.3  $\mu$ m; spacing 2.8  $\mu$ m; b) High aspect ratio honeycomb pattern on PDMS substrate, line width 3.2  $\mu$ m; c) Tapping mode height profile of high aspect ratio ZnO pattern shown in Figure 3b. The patterns grew to ~2  $\mu$ m thickness in 5 h time; d) XRD spectrum of ZnO thin films grown at 55 °C. e–f) SEM images of ZnO nanowires grown on channel diffused plasma modified regions of PDMS substrate at different magnifications. Growth time was 15 h. The nanowires were ~3  $\mu$ m long.

The ZnO nanowires grew downwards, following the crystal orientation of the ZnO seeds. The XRD data confirmed the preferential [0001] growth direction of wurtzite ZnO. The growth rate of the nanowires was ~100–200 nm h<sup>-1</sup>. We grew nanowires for periods of 1 to 24 h. In view of the considerable reduction of Zn<sup>2+</sup> ion concentration in the solution due to consumption by growth, it was necessary to replace the nutrient solution after every 10 h to maintain a constant growth rate.

Fig. 4a shows titania patterns formed on a PET substrate. A tapping mode height profile of amorphous titania pattern are shown in Fig. 4b. The formation of titania was confirmed by EDX analysis. The patterns have an average height of 80 nm and a surface roughness of ~30 nm. Patterns of amorphous TiO<sub>2</sub> were obtained by a selective deposition and subsequent hydrolysis of titanium(IV) phenylmethoxide. The precursor was synthesized by reacting titanium(IV) isopropoxide with benzyl alcohol yielding a 0.2 mol dm<sup>-3</sup> solution. The <sup>1</sup>H NMR measurements showed that at least 88 mol% of the isopropoxy ligands were directly exchanged by benzyl alcohol ligands during preparation.<sup>16</sup> By this means the overall reactivity of titanium(IV) precursor was significantly decreased, so that it could have been handled relatively easily in a typical laboratory environment. Sol–gel processing of titanium(IV) alkoxide into titanium oxide gel follows through hydrolysis and condensation reactions.<sup>17</sup>

Depending on hydrolysis ratio, used catalysts, and coordinating alcoholic ligands, different titania morphologies can be obtained.<sup>18</sup> The as-prepared titania is amorphous, but can be converted easily into crystalline rutile or anatase by mild hydrothermal treatment.<sup>19</sup>

Metallic patterns on plastic substrates are important due to their application as interconnects and active components like sensing elements in flexible devices. We used silver-seeded plasma-treated regions of the plastic substrates for site-selective electroless deposition of Ag. Fig. 4c and 4d show an HR-SEM image, and a tapping mode AFM height profile of Ag micropatterns formed over plasma-patterned silver-seeded PC substrate. The patterns have a line width of 8  $\mu$ m and a line spacing of 1.2  $\mu$ m. The deposition time was 15 min for a thickness of 150 nm. The growth rate can be controlled by dilution of the growth solution, and film thickness can be controlled by deposition time.

Conducting polymers such as PEDOT:PSS and polyaniline (PANI) are important materials in the manufacture of flexible devices such as flexible displays. Fig. 5a–c shows an HR-SEM image, a tapping mode AFM 3D topography image and an AFM height profile of PEDOT:PSS patterns spin-coated over a plasma-patterned PDMS substrate made with a silicon stencil. The dot patterns have a diameter of 5  $\mu$ m and a spacing of 5  $\mu$ m between the dots. The height of each PEDOT:PSS dot is 65 nm.

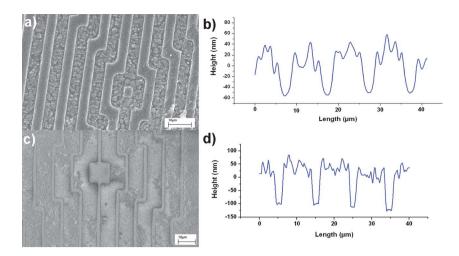


Fig. 4 a) HR-SEM images of TiO<sub>2</sub> patterns on PET substrate. b) Tapping mode AFM height profile of TiO<sub>2</sub> pattern; c) HR-SEM images of Ag micropatterns on PC substrate; d) Tapping mode AFM height profile of Ag pattern grown on PC substrate.

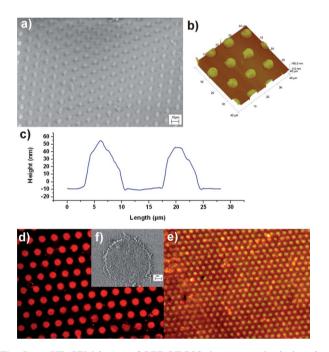


Fig. 5 a) HR-SEM image of PEDOT:PSS dot array selectively spincoated on the hydrophilic regions of the substrate. b) Tapping mode AFM 3D topographic image of PEDOT:PSS dots. c) AFM height profile of PEDOT:PSS dots. d) Optical microscopic image of Au nanoparticle arrays of 5  $\mu$ m dots selectively adsorbed on the stencil patterned substrates; e) optical micrograph of 800 nm dots; f) SEM image of a 5  $\mu$ m dot with adsorbed Au nanoparticles.

Fig. 5d and 5e show optical microscope images and Fig. 5f shows HR-SEM image of Au nanoparticles that were selectively attached on an APTES-patterned PDMS substrate. After plasma modification on PDMS substrates using micro and nanostencils, APTES molecules were selectively bonded to the modified areas. The hydroxyl groups on the oxidized areas of the substrate reacted with APTES and formed a self-assembled molecular thin film. Gold nanoparticles with an average size of 13–15 nm were deposited selectively on the aminosilane areas by immersing the patterned substrates in a colloidal solution of gold nanoparticles. The  $-C_3H_6NH_2$  side chains in the film were protonated at a pH of 2.5 and formed  $-NH_3^+$  end groups which selectively bonded to negatively charged citrate ioncoated Au nanoparticles.

#### Conclusions

We have demonstrated a fast and easy approach to pattern a wide range of functional materials, including ZnO, ZnO nanowires, Au nanoparticles, Ag and PEDOT:PSS on flexible substrates like PDMS, PC and PET by oxygen plasma-modified patterning using PDMS molds or micro/nanostencil shadow masks. We made patterns of arbitrary complexity, with different geometrical features such as lines, anitidots, honey comb and isolated dot arrays. The patterns formed by this technique have feature dimensions as small as 400 nm, up to a few micrometres and cover several square millimetres without defects. Plasma-patterned surface modification using shielding templates is a simple, cost effective and efficient technique to pre-pattern plastic substrates for subsequent site-controlled deposition of metal oxides, metals and organic materials *via* a range of methods, *e.g.* electroless deposition, solution phase deposition, siteselective adsorption and site-selective de-wetting.

#### Acknowledgements

Financial support of NWO-STW in the framework of the Innovational Research Incentive (VIDI scheme) is acknowledged.

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